



Power Bridge Rectifiers

SKD 53

Features

- Glass passivated silicon chips
- Low thermal impedance through use of direct copper bonded aluminum substrate (DCB) base plate
- Blocking voltage up to 1800 V
- Suitable for PCB mounting and wave soldering
- For applications with high vibrations we recommend to fasten the bridge to the pcb with 4 selftapping screw
- UL recognition applied for

Typical Applications*

- Three phase rectifiers for power supplies
- Input rectifiers for variable frequency drives
- Rectifiers for DC motor field supplies
- Battery charger rectifiers

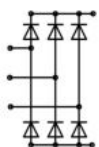
1) Freely suspended or mounted on an insulator

2) Mounted on a painted metal sheet of min. 250 x 250 x 1 mm

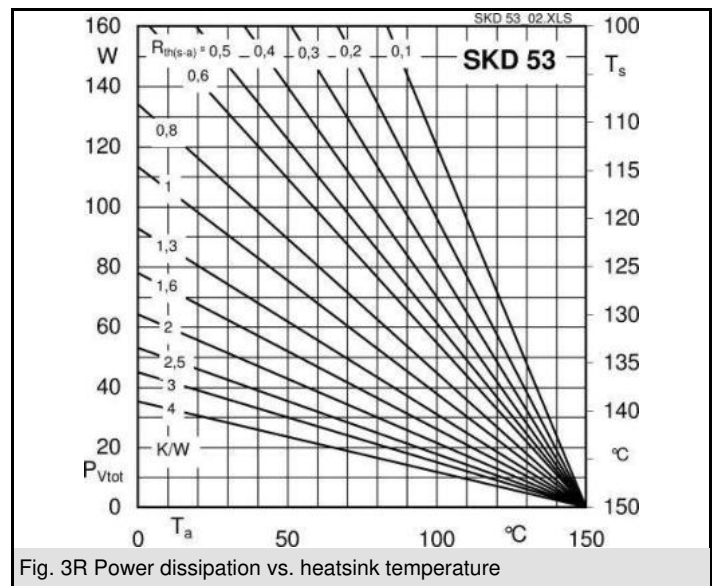
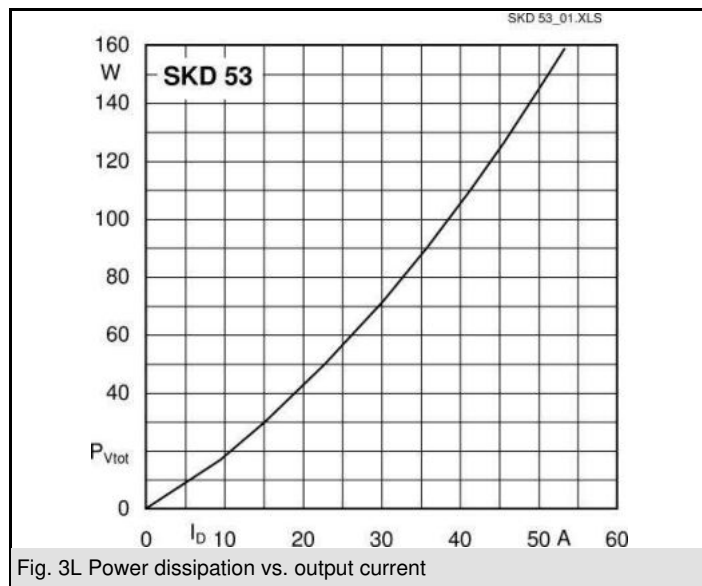
3) $T_{\text{solder}} = 250 \pm 10 \text{ }^{\circ}\text{C}$ (10 s)

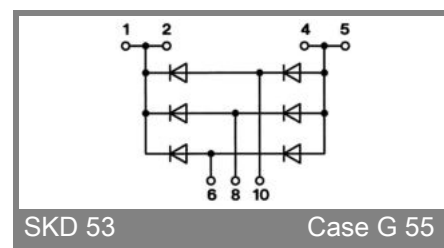
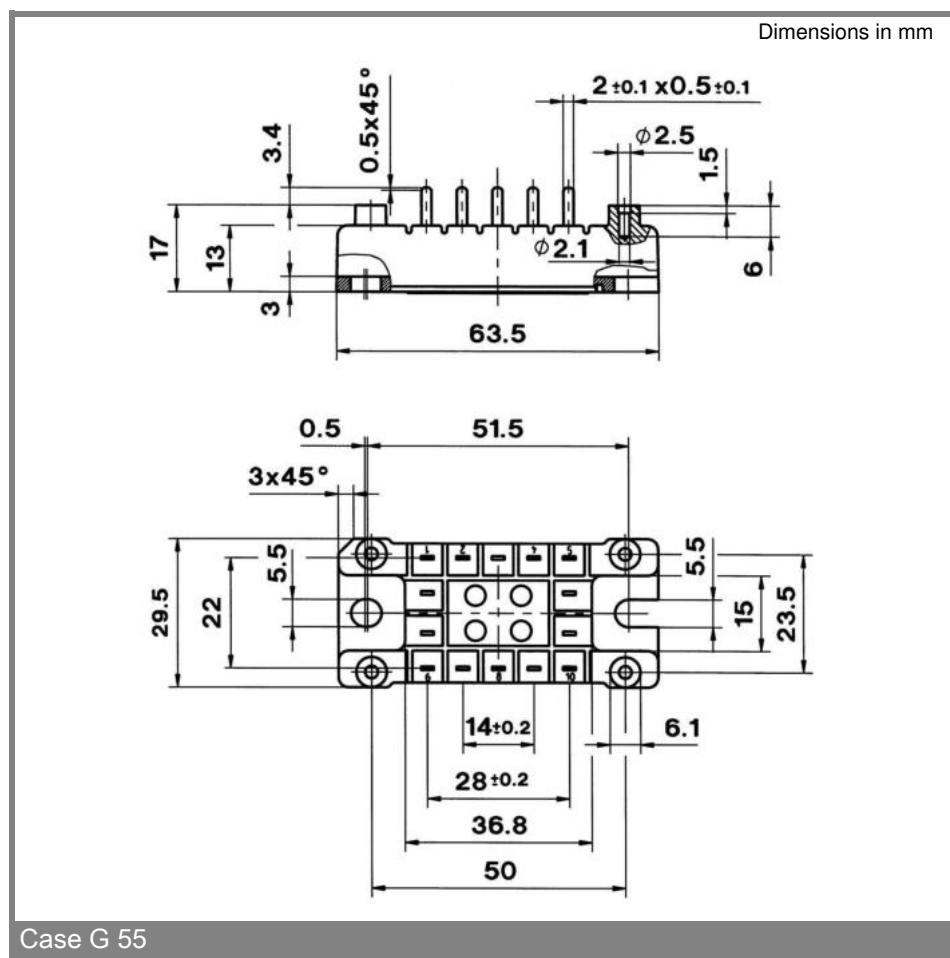
V_{RSM} V	$V_{\text{RRM}}, V_{\text{DRM}}$ V	$I_D = 53 \text{ A}$ (full conduction) ($T_s = 100 \text{ }^{\circ}\text{C}$)
500	400	SKD 53/04
900	800	SKD 53/08
1300	1200	SKD 53/12
1600	1400	SKD 53/14
1700	1600	SKD 53/16
1900	1800	SKD 53/18

Symbol	Conditions	Values	Units
I_D	$T_s = 100 \text{ }^{\circ}\text{C}$	53	A
	$T_a = 45 \text{ }^{\circ}\text{C}$; isolated ¹⁾	4	A
	$T_a = 45 \text{ }^{\circ}\text{C}$; chassis ²⁾	18	A
	$T_a = 45 \text{ }^{\circ}\text{C}$; P5A/100 (R4A/120)	27 (29)	A
	$T_a = 35 \text{ }^{\circ}\text{C}$; P1A/120F	63	A
I_{FSM}	$T_{vj} = 25 \text{ }^{\circ}\text{C}$; 10 ms	370	A
	$T_{vj} = 150 \text{ }^{\circ}\text{C}$; 10 ms	270	A
	$T_{vj} = 25 \text{ }^{\circ}\text{C}$; 8,3 ... 10 ms	685	A ² s
	$T_{vj} = 150 \text{ }^{\circ}\text{C}$; 8,3 ... 10 ms	365	A ² s
V_F	$T_{vj} = 25 \text{ }^{\circ}\text{C}$; $I_F = 50 \text{ A}$	max. 1,5	V
$V_{(T0)}$	$T_{vj} = 150 \text{ }^{\circ}\text{C}$	max. 0,8	V
r_T	$T_{vj} = 150 \text{ }^{\circ}\text{C}$	max. 13	mΩ
I_{RD}	$T_{vj} = 25 \text{ }^{\circ}\text{C}$; $V_{\text{DD}} = V_{\text{DRM}}$; $V_{\text{RD}} = V_{\text{RRM}}$	max. 0,2	mA
	$T_{vj} = 150 \text{ }^{\circ}\text{C}$; $V_{\text{RD}} = V_{\text{RRM}}$	4	mA
$R_{\text{th(j-s)}}$	per diode	1,9	K/W
	total	0,317	K/W
	isolated ¹⁾	14,92	K/W
	chassis ²⁾	2,92	K/W
T_{vj}		- 40 ... + 150	$^{\circ}\text{C}$
T_{stg}		- 40 ... + 125 ³⁾	$^{\circ}\text{C}$
V_{isol}	a. c. 50 Hz; r.m.s.; 1 s / 1 min.	3600 (3000)	V
M_s	to heatsink; SI units	$2 \pm 15 \%$	Nm
M_t			
a		5 * 9,81	m/s ²
m		30	g
Case		G 55	



SKD





* The specifications of our components may not be considered as an assurance of component characteristics. Components have to be tested for the respective application. Adjustments may be necessary. The use of SEMIKRON products in life support appliances and systems is subject to prior specification and written approval by SEMIKRON. We therefore strongly recommend prior consultation of our personal.